



General-purpose Operational Amplifier/Comparator

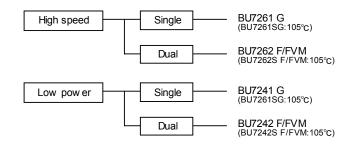
Low Voltage CMOS Operational Amplifier



BU7261G,BU7261SG, BU7241G,BU7241SG, BU7262F/FVM,BU7262S F/FVM, BU7242F/FVM,BU7242S F/FVM

Description

CMOS op-amp BU7261/BU7241 family and BU7262/BU7242 family are input and output full swing op-amp. These ICs integrate one op-amp or two independent op-amps and phase compensation capacitor on a single chip. The features of these ICs are low operating supply Voltage +1.8V to +5.5V(single supply) and low supply current, extremely low input bias current.



Features

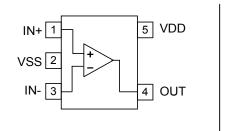
- 1) Low operating supply voltage $(+1.8[V]\sim+5.5[V])$
- 2) +1.8 [V] to+5.5[V](single supply) ±0.9[V] to±2.75[V](split supply)
- 3) Input and Output full swing
- 4) Internal phase compensation
- 5) High slew rate(BU7261 family, BU7262 family)
- 6) Low supply current(BU7241 family, BU7242 family)
- 7) High large signal voltage gain

- B) Internal ESD protection
 Human body model (HBM) ±4000[V](Typ.)
- 9) Wide temperature range
 - $-40[^{\circ}C]$ to $+85[^{\circ}C]$

 $(BU7261G, BU7262\ family,\ BU7241G, BU7242\ family)$

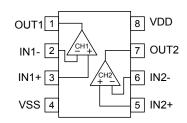
- $-40[^{\circ}C]$ to $+105[^{\circ}C]$
- (BU7261SG,BU7262S family, BU7241SG,BU7242S family)

Pin Assignments



SSOP5

BU7261G BU7261SG BU7241G BU7241SG



SOP8

BU7262F BU7262SF BU7242F BU7242SF

MSOP8

BU7262FVM BU7262SFVM BU7242FVM BU7242SFVM

2007. Octber

Absolute maximum rating (Ta=25[°C])

		Rat	ting						
Parameter	Symbol	BU7261G, BU7262 F/FVM	BU7261SG, BU7262S F/FVM	Uni					
		BU7241G, BU7242 F/FVM	BU7241SG, BU7242S F/FVM						
Supply Voltage	VDD-VSS	+7							
Differential Input Voltage(*1)	Vid	VDD-VSS							
Input Common-mode voltage range	Vicm	(VSS-0.3) to VDD+0.3							
Operating Temperature	Topr	-40 to+85	°C						
Storage Temperature	Tstg	-55 to+125							
Maximum junction Temperature	Tjmax	+125							

Electrical characteristics

○BU7261 series, BU7262series (Unless otherwise specified VDD=+3[V], VSS=0[V], Ta=25[°C])

					Guarant	eed limit						
Parameter	Symbol	Temperature Range		BU7261G BU7261S			7262 F/F 7262S F/I		Unit	Condition		
			Min.	Тур.	Max.	Min.	Тур.	Max.				
Input offset voltage (*2)(*4)	Vio	25℃	-	1	9	-	1	9	mV	VDD=1.8 to 5.5[V], VOUT=VDD/2		
	VIO	Full range	-	-	10	-	-	10	1117	VBB-1.0 to 0.5[v], VOO1=VBB/		
Input offset Current (*2)	lio	25℃	-	1	-	-	1	-	pА	_		
Input Bias Current (*2)	lb	25℃	-	1	-	-	1	-	pА	_		
Supply current (*4)	IDD	25℃	-	250	550	-	550	1100		RL=∞ All Op-Amps		
	טטו	Full range	-	-	600	-	-	1200	μΑ	AV=0[dB],VIN=1.5[V]		
High level output voltage	VOH	25℃	VDD-0.1	-	-	VDD-0.1	-	-	V	RL=10[kΩ]		
Low level output voltage	VOL	25℃	-	-	VSS+0.1	-	-	VSS+0.1	V	RL=10[kΩ]		
Large single voltage gain	AV	25℃	70	95	-	70	95	-	dB	RL=10[kΩ]		
Input common-mode voltage range	Vicm	25℃	0	-	3	0	-	3	V	VDD-VSS=3[V]		
Common-mode rejection ratio	CMRR	25℃	45	60	-	45	60	-	dB	_		
Power supply rejection ratio	PSRR	25℃	60	80	-	60	80	-	dB	-		
Output source current (*3)	IOH	25℃	4	10	-	4	10	-	mA	VDD-0.4[V]		
Output sink current (*3)	IOL	25℃	5	12	-	5	12	-	mA	VSS+0.4[V]		
Slew rate	SR	25℃	-	1.1	-	-	1.1	-	V/µs	CL=25[pF]		
Gain bandwidth product	FT	25℃	-	2	-	-	2	-	MHz	CL=25[pF], AV=40[dB]		
Phase margin	θ	25℃	-	50°	-	-	50°	-	_	CL=25[pF], AV=40[dB]		
Total harmonic distortion	THD	25℃	-	0.05	-	-	0.05	-	%	VOUT=1[Vp-p],f=1[kHz]		
Channel separation	CS	25℃	-	-	-	-	100	-	dB	Av=40[dB]		

Electrical characteristics

○BU7241 series, BU7242 series (Unless otherwise specified VDD=+3[V], VSS=0[V], Ta=25[°C])

					Guarant	eed limit					
Parameter	Symbol	Temperature Range	BU7241G BU7241SG			BU7242F/FVM BU7242S F/FVM			Unit	Condition	
			Min.	Тур.	Max.	Min.	Тур.	Max.			
Input offset voltage (*5)(*7)	Vio	25℃	-	1	9	-	1	9	mV	VDD=1.8 to 5.5[V], VOUT=VDD/2	
	VIO	Full range	-	-	10	-	-	10	IIIV	VDD-1.8 to 5.5[V], VOO1-VDD/2	
Input offset Current (*5)	lio	25℃	-	1	-	-	1	-	pА	_	
Input Bias Current (*5)	lb	25℃	-	1	-	-	1	-	pА	_	
Supply current (*7)	IDD	25℃	-	70	150	-	180	360		RL=∞ All Op-Amps	
	טטו	Full range	-	-	250	-	-	600	μA	AV=0[dB],VIN=1.5[V]	
High level output voltage	VOH	25℃	VDD-0.1	-	-	VDD-0.1	-	-	V	RL=10[kΩ]	
Low level output voltage	VOL	25℃	-	-	VSS+0.1	-	-	VSS+0.1	V	RL=10[kΩ]	
Large single voltage gain	AV	25℃	70	95	-	70	95	-	dB	RL=10[kΩ]	
Input common-mode voltage range	Vicm	25℃	0	-	3	0	-	3	V	VDD-VSS=3[V]	
Common-mode rejection ratio	CMRR	25℃	45	60	-	45	60	-	dB	_	
Power supply rejection ratio	PSRR	25℃	60	80	-	60	80	-	dB	-	
Output source current (*6)	IOH	25℃	4	10	-	4	10	-	mA	VDD-0.4[V]	
Output sink current (*6)	IOL	25℃	5	12	-	5	12	-	mA	VSS+0.4[V]	
Slew rate	SR	25℃	-	0.4	-	-	0.4	-	V/µs	CL=25[pF]	
Gain bandwidth product	FT	25°C	-	0.9	-	-	0.9	-	MHz	CL=25[pF], AV=40[dB]	
Phase margin	θ	25℃	-	50°	-	-	50°	-	_	CL=25[pF], AV=40[dB]	
Total harmonic distortion	THD	25°C	-	0.05	-	-	0.05	-	%	VOUT=1[Vp-p],f=1[kHz]	
Channel separation	CS	25℃	-	-	-	-	100	-	dB	Av=40[dB]	

Absolute value

Note: Absolute maximum rating item indicates the condition which must not be exceeded.

Application of voltage in excess of absolute maximum rating or use out absoluted maximum rated temperature environment may cause deterioration of characteristics.

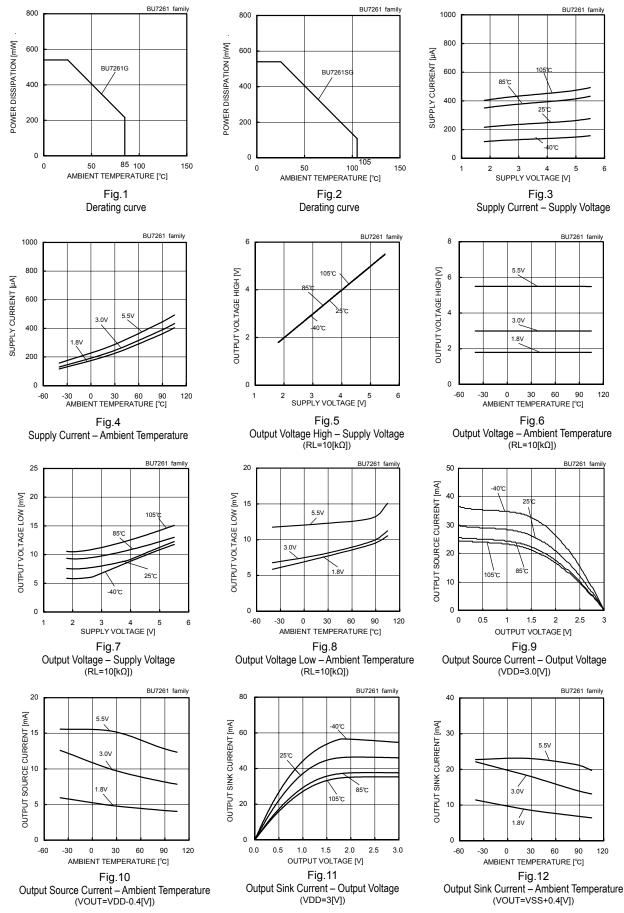
(*1) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more then VEE.

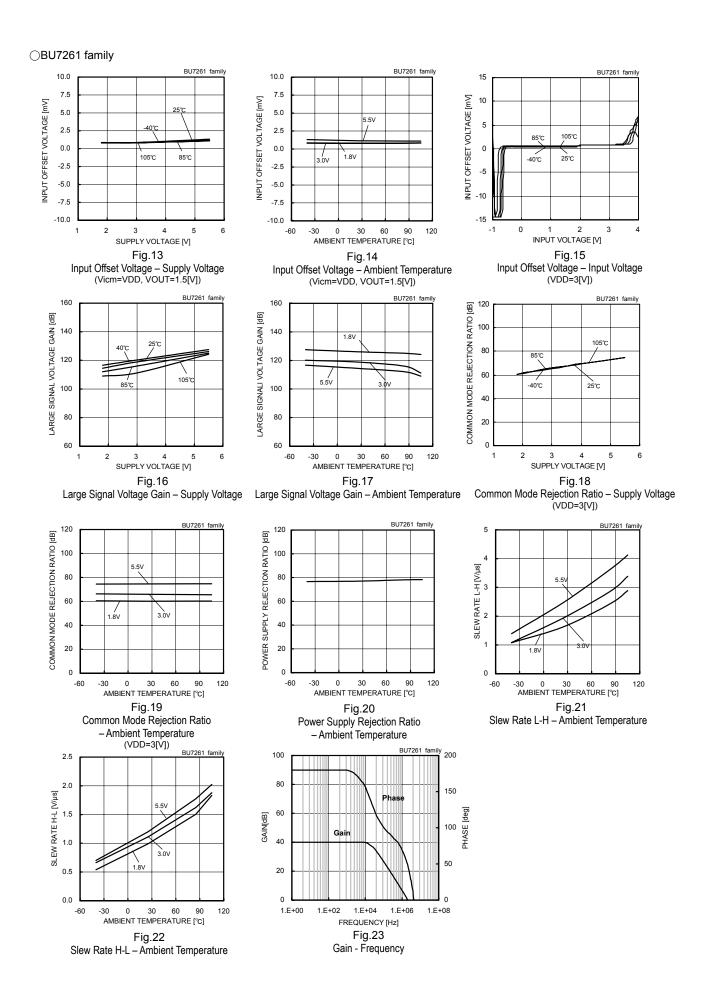
^(*2) Absolute value
(*3) Under the high temperature environment, consider the power dissipation of IC when selecting the output current.
When the terminal shot circuits are continuously output, the output current is reduced to climb to the temperature inside IC.
(*4) Full range: BU7261, BU7262: Ta=-40[°C] to +85[°C] BU7261S, BU7262S: Ta=-40[°C] to +105[°C]

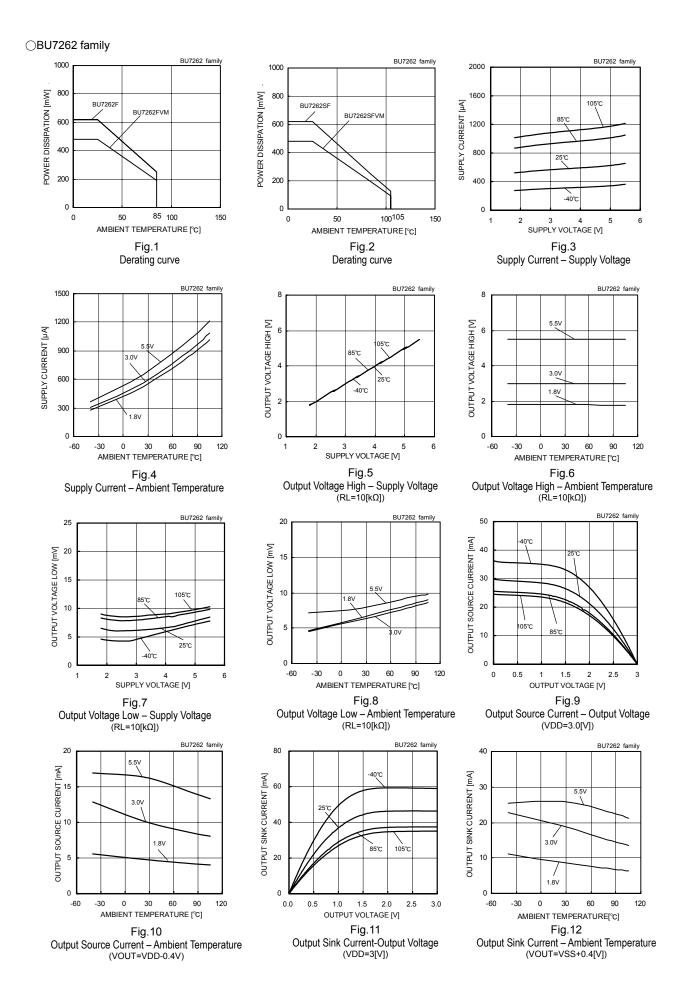
Under the high temperature environment, consider the power dissipation of IC when selecting the output current. When the terminal shot circuits are continuously output, the output current is reduced to climb to the temperature inside IC. Full range: BU7241, BU7242: Ta=-40[°C] to +85[°C] BU7241S, BU7242S: Ta=-40[°C] to +105[°C]

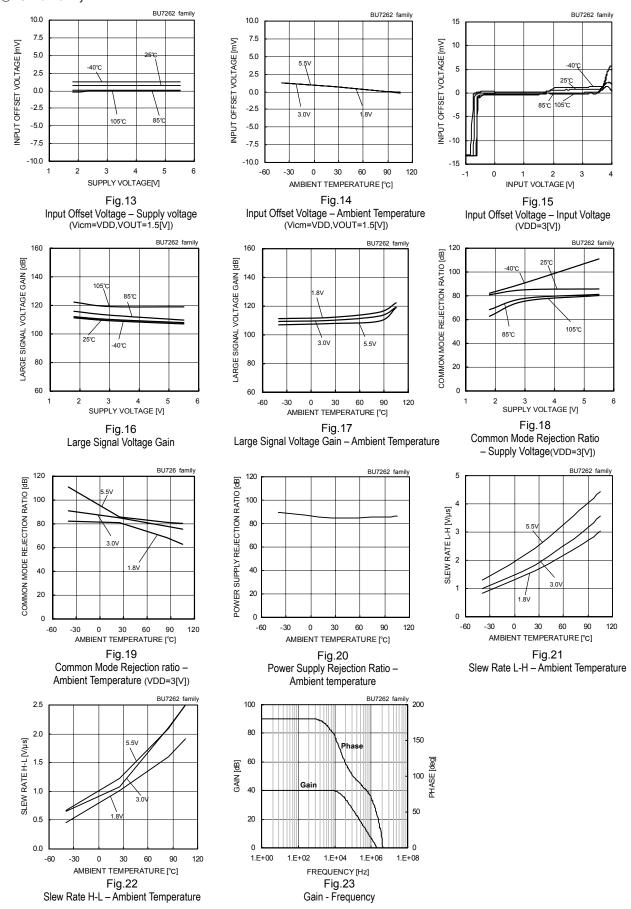
■Example of electrical characteristics ○BU7261 family

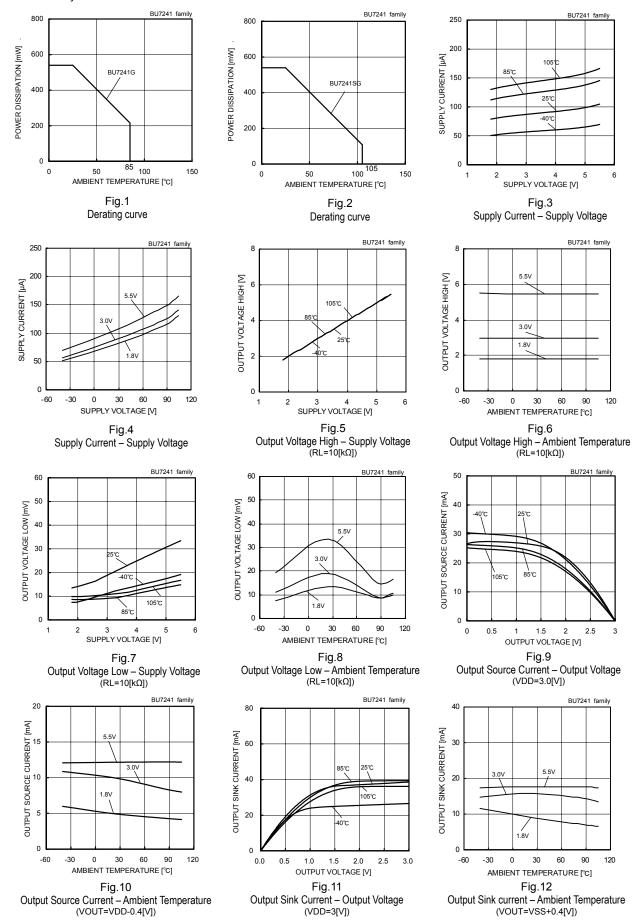


(*) The above date is ability value of sample, it is not guaranteed. BU7261G: $-40[^{\circ}C]$ to $+85[^{\circ}C]$ BU7261SG: $-40[^{\circ}C]$ to $+105[^{\circ}C]$

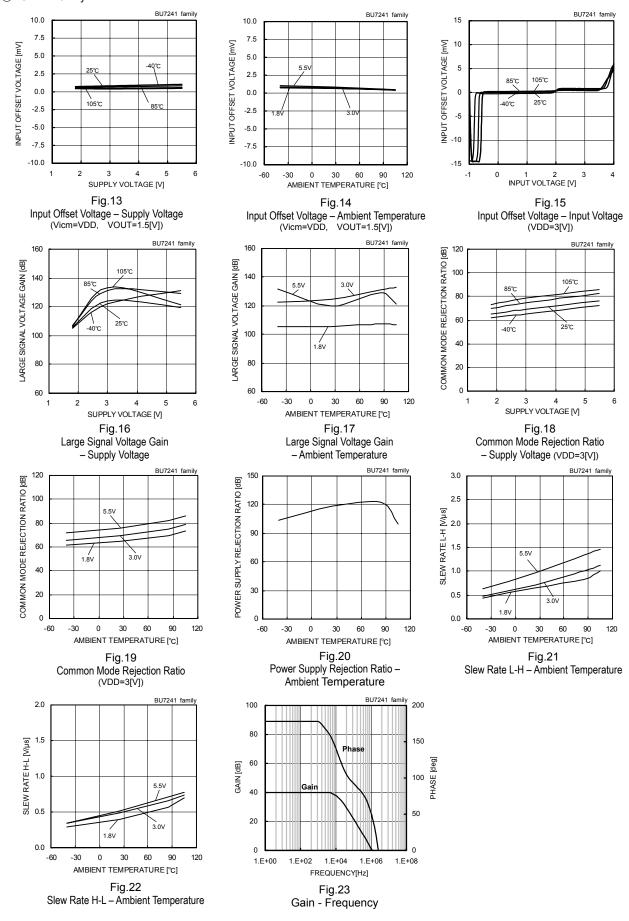




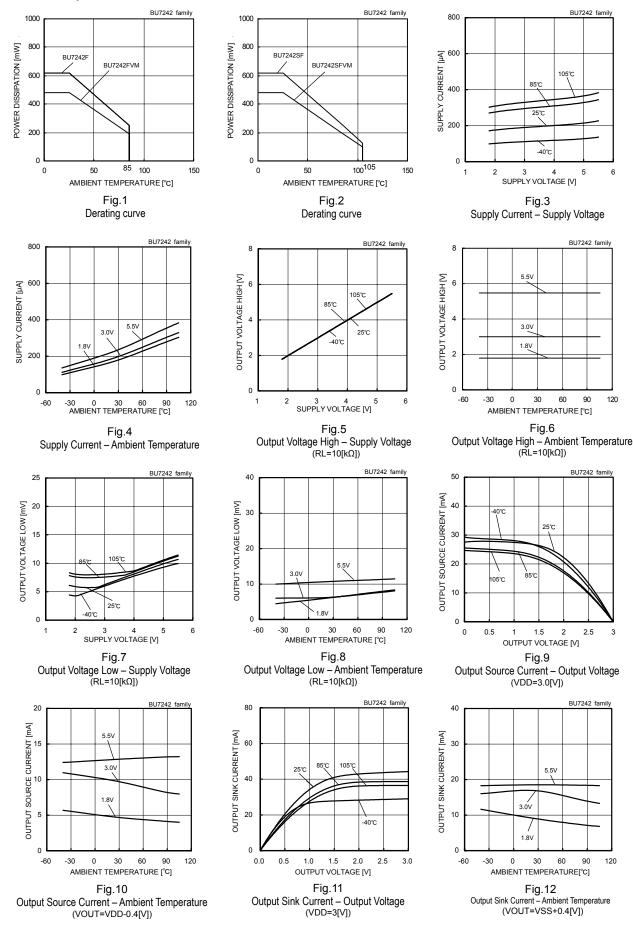


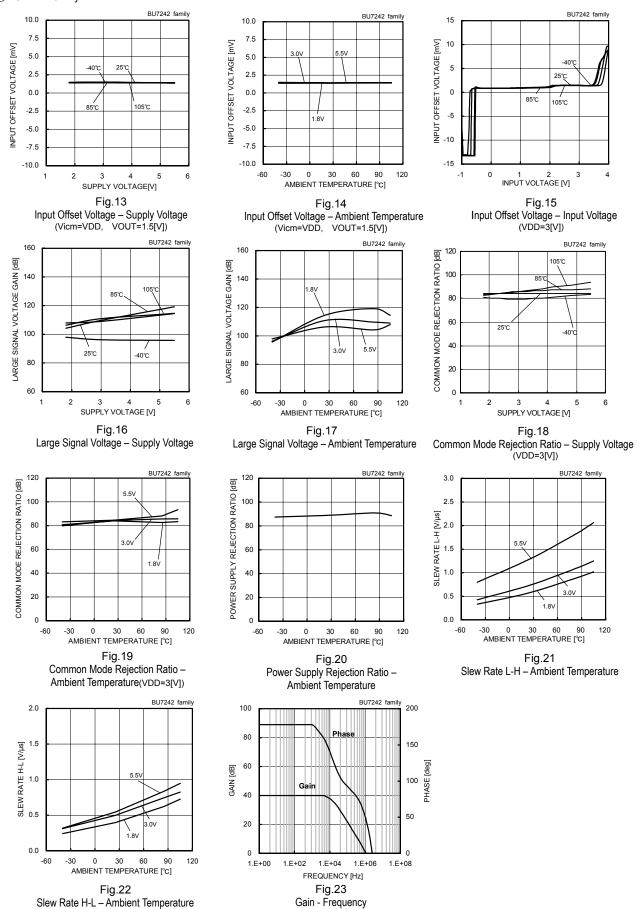


○BU7241 family



(*) The above date is ability value of sample, it is not guaranteed. BU7241G: $-40[^{\circ}C]$ to $+85[^{\circ}C]$ BU7241SG: $-40[^{\circ}C]$ to $+105[^{\circ}C]$





Schematic diagram

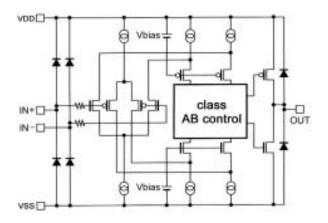


Fig.1 simplified schematic

Test circuit1 NULL method

VDD, VSS, EK, Vicm Unit: [V]

Parameter	VF	S1	S2	S3		Calculation			
Farameter	VF	31	31 32		VDD	VSS	EK	Vicm	Calculation
Input offset voltage	VF1	ON	ON	OFF	3	0	-1.5	3	1
Lorgo signal valtago gain	VF2	ON	ON	ON	3	0	-0.5	1.5	2
Large signal voltage gain	VF3					U	-2.5		2
Common-mode rejection ratio	VF4	ON	ON	OFF	3	0	-1.5	0	3
(Input common-modé voltage range)	VF5	ON ON		OFF	3	U	-1.5	3	3
Device events asian in anti-	VF6	ON	ON	OFF	1.8	0	-0.9	0	4
Power supply rejection ratio	VF7	ON	ON	OFF	5.5	0			4

- Calculation -
- 1. Input offset Voltage (Vio)

2. Large signal voltage gain (Av)

$$Av = 20Log \frac{2 \times (1+Rf/Rs)}{IVF2\cdot VF3I} [dB]$$

- 3. Common-mode rejection ratio (CMRR) CMRR = $20 \text{Log} \frac{3 \times (1 + \text{Rt/Rs})}{|VF4 VF5|}$ [dB
- 4. Power supply rejection ratio (PSRR) $PSRR = 20Log \frac{3.7 \times (1 + RBR8)}{|VF8 VF7|} [dB]$

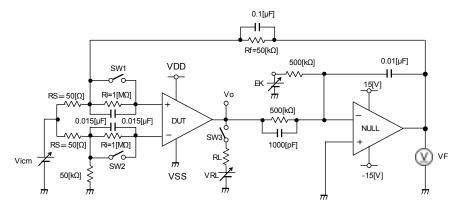
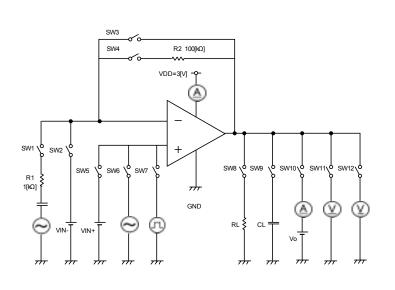


Fig.2 Test Circuit 1 (one channel only)

Test circuit2 switch condition

Unit: [V]												
SW No.	SW 1	SW 2	SW 3	SW 4	SW 5	SW 6	SW 7	SW 8	SW 9	SW 10	SW 11	SW 12
Supply current	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF
maximum output voltage RL=10 [kΩ]	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF
output current	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF
Slew rate	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	ON
maximum frequency	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	ON	OFF	OFF	ON



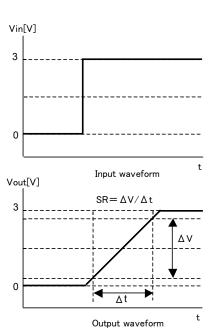


Fig3. Test circuit2 (one channel only)

Fig4. Slew rate input output wave

● Test circuit3 Channel separation

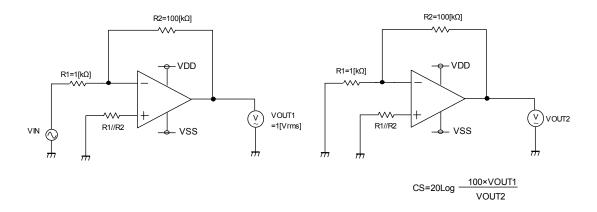


Fig5. Test circuit3

Description of electrical characteristics

Described here are the terms of electric characteristics used in this technical note. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacture's document or general document.

1. Absolute maximum ratings

Absolute maximum rating item indicates the condition which must not be exceeded. Application of voltage in excess of absolute Maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of dharacteristics.

1.1 Power supply voltage (VDD/VSS)

Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.

Differential input voltage (Vid)

Indicates the maximum voltage that can be applied between non-inverting terminal and inverting terminal without deterioration and destruction of characteristics of IC.

1.3 Input common-mode voltage range (Vicm)

Indicates the maximum voltage that can be applied to non-inverting terminal and inverting terminal without deterioration or destruction of characteristics. Input common-mode voltage range of the maximum ratings not assure normal operation of IC. When normal Operation of IC is desired, the input common-mode voltage of characteristics item must be followed.

Power dissipation (Pd)

Indicates the power that can be consumed by specified mounted board at the ambient temperature 25°C (normal temperature). As for package product, Pd is determined by the temperature that can be permitted by IC chip in the package (maximum junction temperature) and thermal resistance of the package

2. Electrical characteristics item

Input offset voltage (Vio)

Indicates the voltage difference between non-inverting terminal and inverting terminal. It can be translated into the input voltage difference required for setting the output voltage at 0 [V]

Input offset current (lio)

Indicates the difference of input bias current between non-inverting terminal and inverting terminal.

Input bias current (lb)

Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias current at non-inverting terminal and input bias current at inverting terminal.

Circuit current (ICC)

Indicates the IC current that flows under specified conditions and no-load steady status.

High level output voltage / Low level output voltage (VOH/VOL) Indicates the voltage range that can be output by the IC under specified load condition. It is typically divided into high-level output voltage and low-level output voltage. High-level output voltage indicates the upper limit of output voltage. Low-level output voltage indicates the lower limit.

Large signal voltage gain (AV)

Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.

Av = (Output voltage fluctuation) / (Input offset fluctuation)

Input common-mode voltage range (Vicm)

Indicates the input voltage range where IC operates normally.

2.8 Common-mode rejection ratio (CMRR)

Indicates the ratio of fluctuation of input offset voltage when in-phase input voltage is changed. It is normally the fluctuation of DC. CMRR = (Change of Input common-mode voltage) / (Input offset fluctuation)

2.9 Power supply rejection ratio (PSRR)

Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC. PSRR= (Change of power supply voltage) / (Input offset fluctuation)

2.10 Channel separation (CS)

Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.

2 11 Slew rate (SR)

Indicates the time fluctuation ratio of voltage output when step input signal is applied

2.12 Unity gain frequency (ft)

Indicates a frequency where the voltage gain of Op-Amp is 1.

2.13 Total harmonic distortion + Noise (THD+N)

Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel

2.14 Input referred noise voltage (Vn)

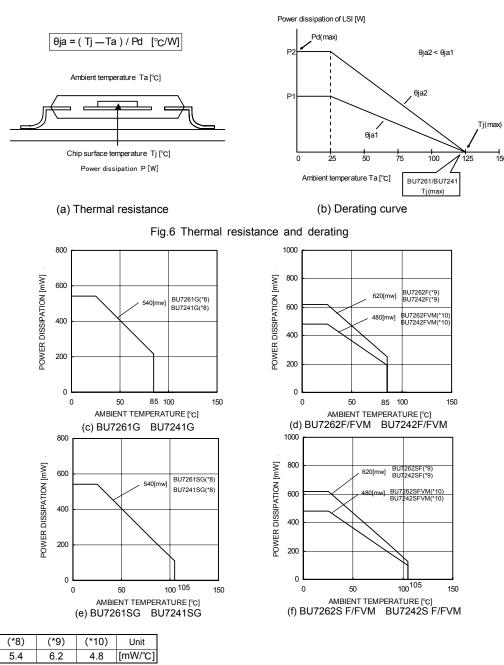
Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input terminal

Derating curve

Power dissipation (total loss) indicates the power that can be consumed by IC at Ta=25°C (normal temperature). IC is heated when it consumed power, and the temperature of IC ship becomes higher than ambient temperature. The temperature that can be accepted by IC chip depends on circuit configuration, manufacturing process, and consumable power is limited. Power dissipation is determined by the temperature allowed in IC chip (maximum junction temperature) and thermal resistance of package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage temperature range. Heat generated by consumed power of IC radiates from the mold resin or lead frame of the package. The parameter which indicates this heat dissipation capability (hardness of heat release) is called thermal resistance, represented by the symbol θ j-a[°C/W]. The temperature of IC inside the package can be estimated by this thermal resistance. Fig.6 (a) shows the model of thermal resistance of the package. Thermal resistance θ ja, ambient temperature Ta, junction temperature Tj, and power dissipation Pd can be calculated by the equation below:

$$\theta$$
ja = $(Tj-Ta)/Pd$ [°C/W] \cdots (1)

Derating curve in Fig.6 (b) indicates power that can be consumed by IC with reference to ambient temperature. Power that can be consumed by IC begins to attenuate at certain ambient temperature. This gradient iis determined by thermal resistance θ ja. Thermal resistance θ ja depends on chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Fig7(c)-(f) show a derating curve for an example of BU7261series, BU7262series, BU7241,BU7242series.



When using the unit above Ta=25[°C], subtract the value above per degree[°C]. Permissible dissipation is the value when FR4 glass epoxy board $70[mm] \times 70[mm] \times 1.6[mm]$ (cooper foil area below 3[%]) is mounted.

Fig.7 Derating Curve

Cautions on use

1) Absolute maximum ratings

Absolute maximum ratings are the values which indicate the limits, within which the given voltage range can be safely charged to the terminal. However, it does not guarantee the circuit operation.

2) Applied voltage to the input terminal

For normal circuit operation of voltage comparator, please input voltage for its input terminal within input common mode voltage VDD+0.3[V]. Then, regardless of power supply voltage,VSS-0.3[V] can be applied to input terminals without deterioration or destruction of its characteristics.

3) Operating power supply (split power supply/single power supply)

The voltage comparator operates if a given level of voltage is applied between VDD and VSS. Therefore, the operational amplifier can be operated under single power supply or split power supply.

4) Power dissipation (pd)

If the IC is used under excessive power dissipation. An increase in the chip temperature will cause deterioration of the radical characteristics of IC.

For example, reduction of current capability. Take consideration of the effective power dissipation and thermal design with a sufficient margin. Pd is reference to the provided power dissipation curve.

5) Short circuits between pins and incorrect mounting

Short circuits between pins and incorrect mounting when mounting the IC on a printed circuits board, take notice of the direction and positioning of the IC.

If IC is mounted erroneously, It may be damaged. Also, when a foreign object is inserted between output, between output and VDD terminal or VSS terminal which causes short circuit, the IC may be damaged.

6) Using under strong electromagnetic field

Be careful when using the IC under strong electromagnetic field because it may malfunction.

7) Usage of IC

When stress is applied to the IC through warp of the printed circuit board, The characteristics may fluctuate due to the piezo effect.

Be careful of the warp of the printed circuit board.

8) Testing IC on the set board

When testing IC on the set board, in cases where the capacitor is connected to the low impedance, make sure to discharge per fabrication because there is a possibility that IC may be damaged by stress. When removing IC from the set board, it is essential to cut supply voltage.

As a countermeasure against the static electricity, observe proper grounding during fabrication process and take due care when carrying and storage it.

9) The IC destruction caused by capacitive load

The transistors in circuits may be damaged when VDD terminal and VSS terminal is shorted with the charged output terminal capacitor. When IC is used as a operational amplifier or as an application circuit, where oscillation is not activated by an output capacitor, the output capacitor must be kept below $0.1[\mu F]$ in order to prevent the damage mentioned above.

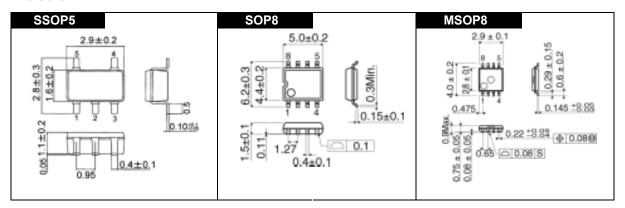
10) Decupling capacitor

Insert the deculing capacitance between VDD and VSS, for stable operation of operational amplifier.

11) Latch up

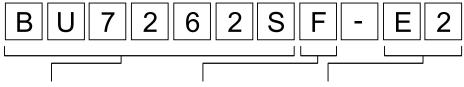
Be careful of input vltage that exceed the VDD and VSS. When CMOS device have sometimes occur latch up operation. And protect the IC from abnormaly noise

Dimensions



Model number construction

- Specify the product by the model number when placing an order.
 Make sure of the combinations of items.
- Start with the leftmost space without leaving any empty space between characters.



ROHM product name

- BU7261 BU7261S
- BU7241 BU7241S - BU7262 BU7262S
- BU7242 BU7242S

Package type

- G : SSOP5 F : SOP8 • FVM : MSOP8
- E2 Embossed tape on reel with pin 1 near far when pulled out TR Embossed tape on reel with pin 1 near far when pulled out

Packing specification reference

Package	Packing specification name	Quantity	Embossed carrier tape
SSOP5	TR	3000	Reel Direction of feed
SOP8	E2	2500	Real Direction of feed
MSOP8	TR	3000	Reel Direction of feed

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
 means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
 product described in this document are for reference only. Upon actual use, therefore, please request
 that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
 use and operation. Please pay careful attention to the peripheral conditions when designing circuits
 and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
 otherwise dispose of the same, no express or implied right or license to practice or commercially
 exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact your nearest sales office.

ROHM Customer Support System

THE AMERICAS / EUPOPE / ASIA / JAPAN

www.rohm.com

Contact us : webmaster@ rohm.co.jp

Copyright © 2007 ROHM CO.,LTD.

ROHM CO., LTD. 21, Saiin Mizosaki-cho, Ukyo-ku, Kyoto 615-8585, Japan

TEL:+81-75-311-2121 FAX:+81-75-315-0172



Appendix1-Rev2.0